## SCHOTTKY BARRIER DIODE

## Features

- Ultra high-speed switching
- Very low forward voltage
- Very small SMD plastic package


## Applications

- Ultra high-speed switching
- Voltage clamping
- Protection circuits

PINNING

| PIN | DESCRIPTION |
| :---: | :--- |
| 1 | Cathode |
| 2 | Anode |



Top View
Marking Code: "FP"
Simplified outline SOD-323 and symbol

Absolute Maximum Ratings ( $\mathrm{T}_{\mathrm{a}}=25^{\circ} \mathrm{C}$ )

| Parameter | Symbol | Value | Unit |
| :--- | :---: | :---: | :---: |
| Reverse Voltage | $\mathrm{V}_{\mathrm{R}}$ | 20 | V |
| Continuous Forward Current | $\mathrm{I}_{\mathrm{F}}$ | 1 | A |
| Non-repetitive Peak Forward Current ( $\mathrm{t}=8.3 \mathrm{~ms} \mathrm{Half} \mathrm{Sine}$ <br> Wave, JEDEC method) | $\mathrm{I}_{\text {FSM }}$ | 5 | A |
| Junction Temperature | $\mathrm{T}_{J}$ | 125 | ${ }^{\circ} \mathrm{C}$ |
| Operating Ambient Temperature Range | $\mathrm{T}_{\text {op }}$ | -65 to +125 | ${ }^{\circ} \mathrm{C}$ |
| Storage Temperature Range | $\mathrm{T}_{\text {stg }}$ | -65 to +150 | ${ }^{\circ} \mathrm{C}$ |
| Thermal Resistance from Junction to Ambient | $\mathrm{R}_{\text {өJA }}$ | $220^{1)}$ | ${ }^{2)}$ |

${ }^{1)}$ Mounted on P.C.B. $10 \times 10 \mathrm{~mm}^{2} \mathrm{Cu}$
${ }^{2)}$ Mounted on P.C.B. $40 \times 40 \mathrm{~mm}^{2} \mathrm{Cu}$

Characteristics at $\mathrm{T}_{\mathrm{a}}=25^{\circ} \mathrm{C}$

| Parameter | Symbol | Max. | Unit |
| :--- | :---: | :---: | :---: |
| Forward Voltage |  |  |  |
| at $I_{F}=10 \mathrm{~mA}$ | $\mathrm{~V}_{\mathrm{F}}$ | 0.27 | V |
| at $\mathrm{I}_{\mathrm{F}}=100 \mathrm{~mA}$ |  | 0.35 |  |
| at $\mathrm{I}_{\mathrm{F}}=1 \mathrm{~A}$ |  | 0.65 |  |
| Reverse Current |  |  |  |
| at $\mathrm{V}_{\mathrm{R}}=5 \mathrm{~V}$ | $\mathrm{I}_{\mathrm{R}}$ | 10 | MA |
| at $\mathrm{V}_{\mathrm{R}}=8 \mathrm{~V}$ |  | 20 |  |
| at $\mathrm{V}_{\mathrm{R}}=15 \mathrm{~V}$ |  | 50 | pF |
| Diode Capacitance | $\mathrm{C}_{\mathrm{d}}$ | 25 |  |
| at $\mathrm{V}_{\mathrm{R}}=5 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ |  |  |  |


(1) $T_{m b}=85 c$
(2) $\mathrm{T}_{\mathrm{ma}}=25^{\circ} \mathrm{C}$
(3) $T_{m=0}=-40^{\circ} \mathrm{C}$.

Forward current as a function of forward voltage; typical values.


## $\mathrm{T}_{\text {min }}=25^{\circ} \mathrm{G} \mathrm{f}=1 \mathrm{MHz}$

Diode capacitance as a function of reverse voltage; typical values.

(i) $\mathrm{T}_{\mathrm{mab}}=125^{\circ} \mathrm{C}$.
(2) $\mathrm{T}_{\mathrm{mb}}=86^{\circ} \mathrm{C}$.
(3) $\mathrm{T}_{\mathrm{mb}}=25^{\circ} \mathrm{C}$.

Reverse current as a function of reverse voltage; typical values.

## PACKAGE OUTLINE



| Symbol | Dimension in Millimeters |  |
| :---: | :---: | :---: |
|  | Min | Max |
| A | 0.95 | 1.15 |
| A1 | 0.010 | 0.100 |
| B | 1.20 | 1.40 |
| bp | 0.25 | 0.40 |
| C | 0.09 | 0.150 |
| E | 1.60 | 1.80 |
| HE | 2.30 | 2.70 |
| Lp | 0.20 | 0.40 |
| $\theta$ | $0^{\circ}$ | $5^{\circ}$ |

